



50V N-Channel Enhancement Mode MOSFET - ESD Protected

Voltage 50 V Current 350mA

Features

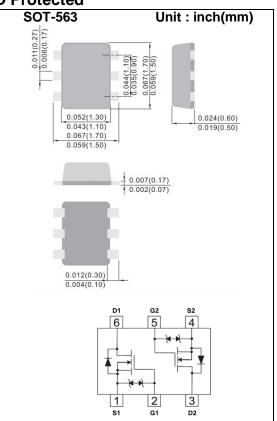
- RDS(ON), VGS@10V, ID@500mA<1.6Ω
- RDS(ON), VGS@4.5V, ID@200mA<2.5Ω
- RDS(ON), VGS@2.5V, ID@100mA<4.5Ω
- Advanced Trench Process Technology
- Specially Designed for Battery Operated Systems, Solid-State Relays Drivers: Relay, Displays, Memories, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

Case: SOT-563 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.00009 ounces, 0.0026 grams



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	50	V
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V
Continuous Drain Current		I _D	350	mA
Pulsed Drain Current		I _{DM}	1200	mA
Power Dissipation	T _A =25°C	P _D	223	mW
	Derate above 25°C		1.8	mW/°C
Operating Junction and Storage Temperature Range		T_{J}, T_{STG}	-55~150	°C
Typical Thermal resistance - Junction to Ambient (Note 3)		$R_{ heta JA}$	560	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V _{GS} =0V,I _D =250uA	50	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	0.8	1.0	1.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =500mA	-	0.96	1.6	Ω
		V _{GS} =4.5V,I _D =200mA	-	1.25	2.5	
		V _{GS} =2.5V,I _D =100mA	-	2.73	4.5	
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} =50V, V_{GS} =0V	-	0.01	1	uA
Gate-Source Leakage Current	I_{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	<u>+</u> 3.0	<u>+</u> 10	uA
Dynamic						
Total Gate Charge	Q_g	V _{DS} =25V, I _D =250mA, V _{GS} =4.5V ^(Note 1,2)	-	0.63	1	nC
Gate-Source Charge	Q_gs		-	0.2	-	
Gate-Drain Charge	Q_gd		-	0.23	-	
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V, f=1.0MHZ	-	25	50	pF
Output Capacitance	Coss		-	9.5	20	
Reverse Transfer Capacitance	Crss	I=1.UIVIAZ	-	2.1	5	
Switching						
Turn-On Delay Time	td _(on)	\/ O5\/ 500 ·· A	-	2.2	5	ns
Turn-On Rise Time	tr	$\begin{array}{c} V_{DD}{=}25V,\ I_{D}{=}500mA,\\ V_{GS}{=}10V,\\ R_{G}{=}6\Omega \end{array}$	-	19.2	38	
Turn-Off Delay Time	td _(off)		-	6.2	12	
Turn-Off Fall Time	tf		-	23	50	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S		-	-	500	mA
Diode Forward Voltage	V _{SD}	I _S =500mA, V _{GS} =0V	-	0.86	1.5	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R_{BUA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. mounted on a 1 inch square pad of copper





TYPICAL CHARACTERISTIC CURVES

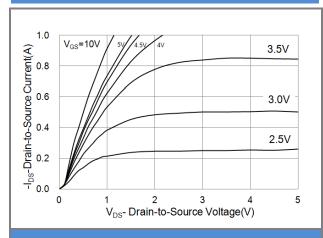


Fig.1 On-Region Characteristics

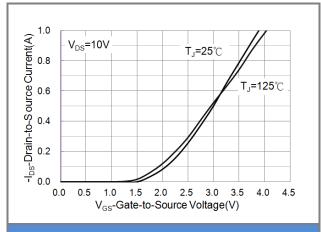


Fig.2 Transfer Characteristics

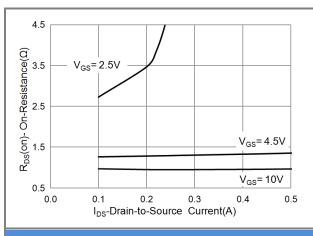


Fig.3 On-Resistance vs. Drain Current

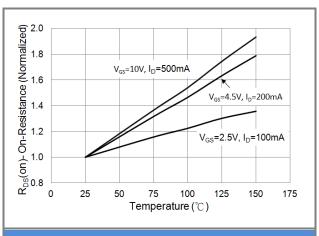


Fig.4 On-Resistance vs. Junction temperature

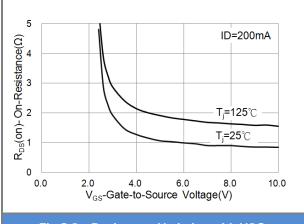


Fig.5 On-Resistance Variation with VGS.

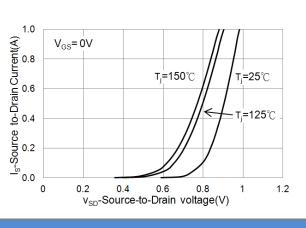


Fig.6 Body Dlode CharacterIsIcs





TYPICAL CHARACTERISTIC CURVES

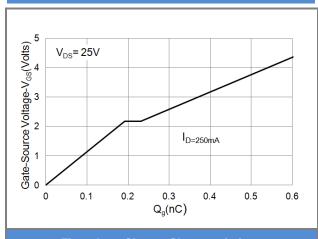


Fig.7 Gate-Charge Characteristics

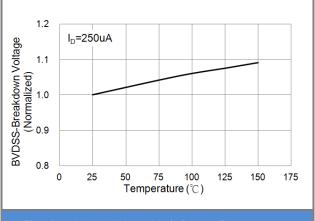


Fig.8 Breakdown Voltage Variation vs. Temperature

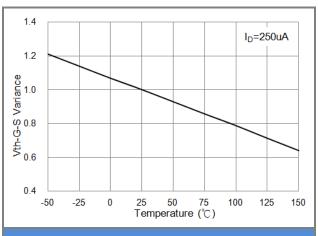


Fig.9 Threshold Voltage Variation with Temperature.

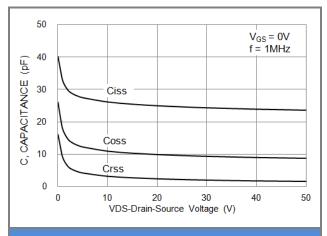


Fig.10 Capacitance vs. Drain-Source Voltage.

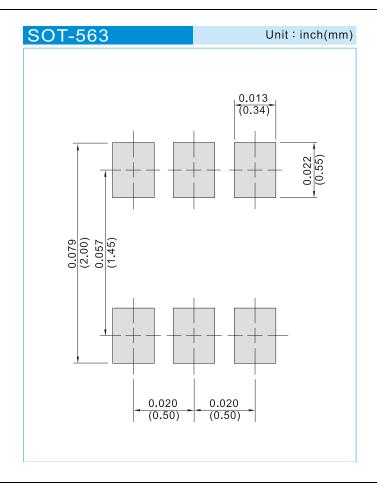




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJX138K_R1_00001	SOT-563	4K pcs / 7" reel	8KB	Halogen free
PJX138K_R2_00001	SOT-563	10K pcs / 13" reel	8KB	Halogen free
PJX138K_R1_00002	SOT-563	8K pcs / 7" reel	8KB	Halogen free
PJX138K_R2_00002	SOT-563	20K pcs / 13" reel	8KB	Halogen free

MOUNTING PAD LAYOUT







Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are
 responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no
 representation or warranty that such applications will be suitable for the specified use without further testing or
 modification.
- The products shown herein are not designed and authorized for equipments requiring high level of reliability or relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, transportation equipment, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.